## **ANURAG Engineering College**

(An Autonomous Institution)

## I B.Tech II Semester Supplementary Examinations, Jan/Feb-2024 ELECTRONIC DEVICES AND CIRCUITS (ELECTRONICS AND COMMUNICATION ENGINEERING)

Time: 3 Hours Max. Marks: 75 Section – A (Short Answer type questions) (25 Marks) Course B.T Marks **Answer All Questions** Level Outcome 1. Define zener break down. CO<sub>1</sub> L1 2M 2. Find ripple factor for Half wave Rectifier? CO<sub>1</sub> L1 3M 3. What is pinch-off voltage? Give its expression. CO<sub>2</sub> L1 2M 4. Compare CB, CE and CC configurations of a transistor CO<sub>2</sub> L2 3M 5. What is the need for biasing? CO<sub>3</sub> L1 2M6. Explain when a FET acts as a voltage variable resistor. L2 CO<sub>3</sub> 3M 7. Sketch a simplified CE Hybrid model of a transistor. CO<sub>4</sub> L1 2M 8. Describe how h<sub>fe</sub> and h<sub>ie</sub> can be determined from BJT characteristics. CO<sub>4</sub> L2 3M 9. What is the difference between amplifier and oscillator? CO<sub>5</sub> L1 2M 10. List any three characteristics of an amplifier which are modified by CO<sub>5</sub> L1 3M negative feedback. **Section B (Essay Questions)** Answer all questions, each question carries equal marks.  $(5 \times 10M = 50M)$ Explain the construction, operation and characteristics of Tunnel CO<sub>1</sub> L2 10M diode. OR B) With neat circuit diagram and waveforms, explain the working of full CO<sub>1</sub> L2 10M wave bridge rectifier with capacitor filter. Illustrate the input and output characteristics of all three CO<sub>2</sub> L2 10M 12. A) configurations of a BJT transistor Also give the important equations related to those configurations. B) Draw and explain construction and operation of Enhancement mode L2 CO<sub>2</sub> 10M MOSFET with its characteristics. L2 13. A) Explain the operation of common emitter BJT circuit with self-bias CO<sub>3</sub> 10M and derive the expression for stability factor S. OR B) What is the difference between bias stabilization & bias L2 CO<sub>3</sub> 10M compensation? With neat diagram determine the h parameters for CE configuration CO<sub>4</sub> L3 10M 14. A)

and calculate current gain, voltage gain, input and output impedances.

Sketch the circuit of a small-signal model of Common drain FET

amplifier and derive the expressions for voltage gain and output

resistance.

10M

L3

CO4

**R15** 

15. A)	Discuss about characteristics of negative feedback amplifiers.	CO5	L3	10M
	OR			
B)	With a neat diagram explain about Hartley, Colpitts oscillator and obtain the expression for frequency of oscillation and conditions for oscillation.	CO5	L2	10M